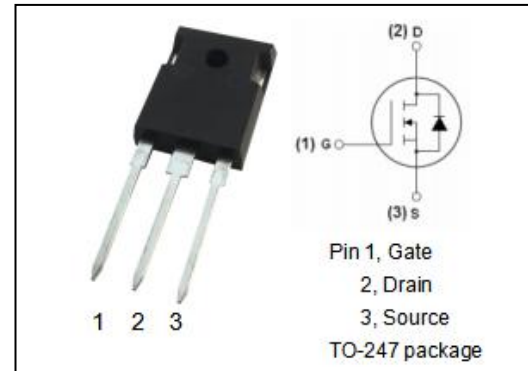


isc N-Channel MOSFET Transistor**FMH20N60S1****FEATURES**

- Static Drain-Source On-Resistance
: $R_{DS(on)} = 190\text{m}\Omega$ (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATION

- Designed for use in switch mode power supplies and general purpose applications.

**ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)**

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	600	V
V_{GS}	Gate-Source Voltage-Continuous	± 30	V
I_D	Drain Current-Continuous	20	A
I_{DM}	Drain Current-Single Pluse	60	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	140	W
T_J	Max. Operating Junction Temperature	-55~150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.89	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS

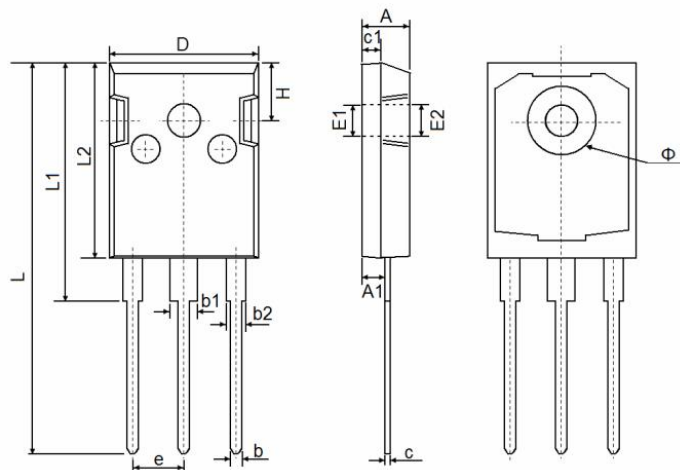
$T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$V_{(BR)DS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0$; $I_D = 250\ \mu\text{A}$	600		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$; $I_D = 250\ \mu\text{A}$	2.5	4	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS} = 10\text{V}$; $I_D = 10\text{A}$		190	$\text{m}\Omega$
I_{GSS}	Gate-Body Leakage Current	$V_{GS} = \pm 30\text{V}$; $V_{DS} = 0$		± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = V_{DSS}$; $V_{GS} = 0$		25	μA
V_{SD}	Forward On-Voltage	$I_S = 20\text{A}$; $V_{GS} = 0$		1.35	V

isc N-Channel MOSFET Transistor

FMH20N60S1

TO-247 PACKAGE INFORMATION



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 REF		0.138 REF	
E2	3.600 REF		0.142 REF	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Φ	7.100	7.300	0.280	0.287
e	5.450 TYP		0.215 TYP	
H	5.980 REF		0.235 REF	

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